

## Controllable Bridge Rectifiers

## **SKCH 28**

## **Features**

- Sturdy isolated metal baseplate
- Fast-on terminals with solder tips
- · Suitable for wave soldering
- · High surge current rating
- UL recognized, file no. E 63 532

## **Typical Applications**

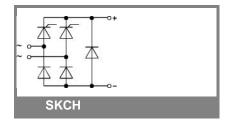
- Controllable single phase rectifierDC power supplies
- DC motor controllers
- . DC motor field controllers

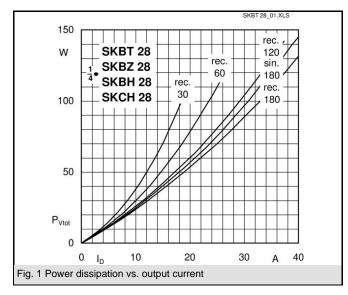
1)	Painted metal shield of minimum 250 x
	250 x 1 mm: R <sub>th(c-a)</sub> = 1,85 K/W

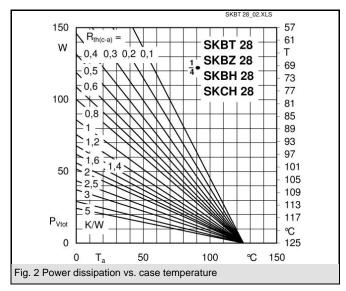
2) Freely suspended or mounted on insulator

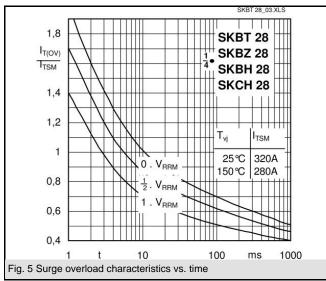
V <sub>RSM</sub>	$V_{RRM}, V_{DRM}$	I <sub>D</sub> = 28 A (full conduction)
V	V	(T <sub>c</sub> = 89 °C)
400	400	SKCH 28/04
600	600	SKCH 28/06
800	800	SKCH 28/08
1200	1200	SKCH 28/12
1400	1400	SKCH 28/14

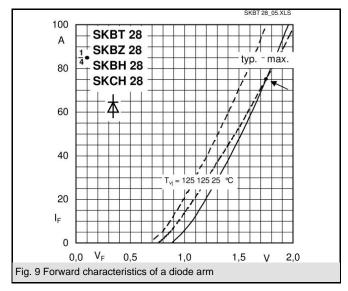
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	Symbol	Conditions	Values	Units
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	I <sub>D</sub>		30	Α
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$			13	Α
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$			15	Α
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		<u>u</u>	16	Α
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$		<u>u</u>	23	Α
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	$I_{TSM}, I_{FSM}$			
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	l			
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	i²t	•,		_
$\begin{array}{cccccccccccccccccccccccccccccccccccc$		•,		_
$ \begin{array}{llllllllllllllllllllllllllllllllllll$		*) ·	max. 2,25	
$ \begin{array}{llllllllllllllllllllllllllllllllllll$	$V_{T(TO)}$		max. 1	V
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	$r_T$	1 3	max. 16	mΩ
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	$I_{DD}; I_{RD}$	$T_{vj}$ = 125 °C; $V_{DD}$ = $V_{DRM}$ ; $V_{RD}$ = $V_{RRM}$	max. 8	mA
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	$t_{gd}$	1 ",	1	μs
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$			1	μs
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	(dv/dt) <sub>cr</sub>	T <sub>vj</sub> = 125 °C	max. 500	V/µs
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	(di/dt) <sub>cr</sub>		max. 50	A/µs
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	t <sub>q</sub>		80	μs
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	I <sub>H</sub>	T <sub>vj</sub> = 25 °C; typ. / max.	50 / 150	mA
$\begin{array}{cccccccccccccccccccccccccccccccccccc$		_ · ·	100 / 300	mA
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$V_{GT}$		min. 2	V
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	I <sub>GT</sub>		min. 100	mA
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$V_{GD}$	$T_{vj}$ = 125 °C; d.c.	max. 0,25	V
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$I_{GD}$	T <sub>vj</sub> = 125 °C; d.c.	max. 3	mA
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	R <sub>th(j-c)</sub>	per thyristor / diode	1,8	
$\begin{array}{cccccccccccccccccccccccccccccccccccc$		total	0,45	K/W
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	R <sub>th(c-s)</sub>		0,1	
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$R_{th(j-a)}$	total <sup>2)</sup>		
V <sub>isol</sub> a. c. 50 Hz; r.m.s.; 1 s / 1 min. 3600 (3000) V   M <sub>s</sub> case to heatsink 2 Nm   M <sub>t</sub> n.a. Nm   m 66 g	$T_{vj}$		- 40 <b>+</b> 125	_
Ms case to heatsink 2 Nm   Mt n.a. Nm   m 66 g			- 40 <b>+</b> 125	°C
Ms case to heatsink 2 Nm   Mt n.a. Nm   m 66 g	$V_{isol}$		` '	
m 66 g	$M_s$	case to heatsink	2	
	$M_t$		n.a.	Nm
Case SKCH G 25	m		66	g
	Case	SKCH	G 25	

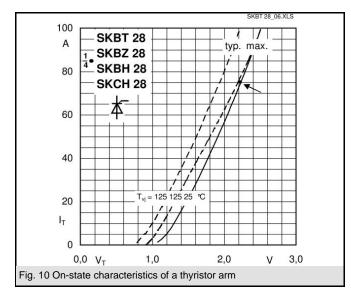


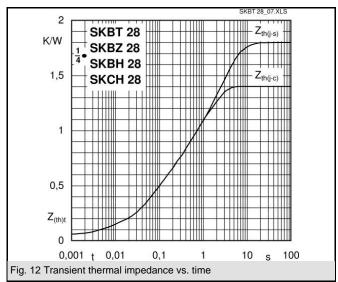


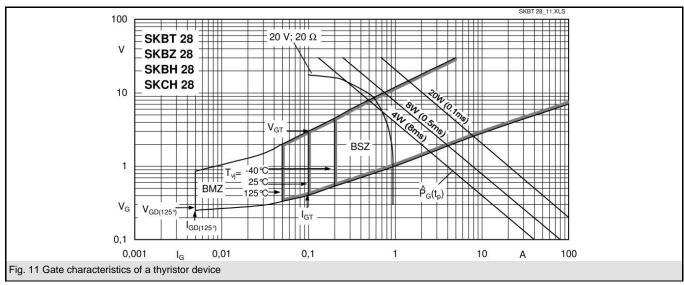


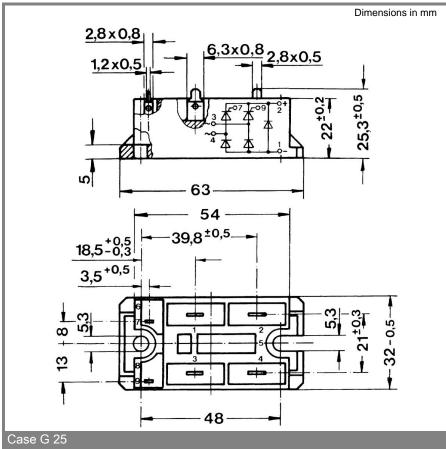












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